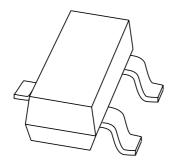
DISCRETE SEMICONDUCTORS

DATA SHEET



BAV99High-speed double diode

Product specification Supersedes data of 1999 May 11 2001 Oct 15





High-speed double diode

BAV99

FEATURES

- Small plastic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- · Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 450 mA.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
BAV99	A7*

Note

- 1. * = p: Made in Hong Kong. * = t: Made in Malaysia. * = W: Made in China.
- PIN **DESCRIPTION** 1 anode 2 cathode 3

common connection

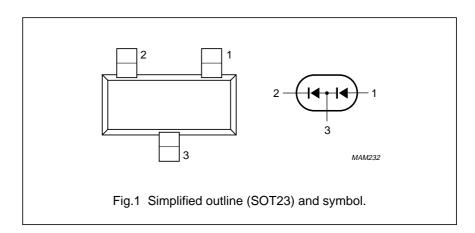
PINNING

APPLICATIONS

· High-speed switching in thick and thin-film circuits.

DESCRIPTION

The BAV99 consists of two high-speed switching diodes connected in series, fabricated in planar technology, and encapsulated in the small SOT23 plastic SMD package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	
Per diode					
V _{RRM}	repetitive peak reverse voltage		_	85	V
V _R	continuous reverse voltage		_	75	V
l _F	continuous forward current	single diode loaded; see Fig.2; note 1	_	215	mA
		double diode loaded; see Fig.2; note 1	_	125	mA
I _{FRM}	repetitive peak forward current		_	450	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	4	Α
		t = 1 ms	_	1	Α
		t = 1 s	_	0.5	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
T _i	junction temperature		_	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.

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ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	PARAMETER CONDITIONS			
Per diode					
V _F	forward voltage	see Fig.3			
		I _F = 1 mA	715	mV	
		I _F = 10 mA	855	mV	
		$I_F = 50 \text{ mA}$	1	V	
		I _F = 150 mA	1.25	V	
I _R	reverse current	see Fig.5			
		V _R = 25 V	30	nA	
		V _R = 75 V	1	μΑ	
		V _R = 25 V; T _j = 150 °C	30	μΑ	
		V _R = 75 V; T _j = 150 °C	50	μΑ	
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	1.5	pF	
t _{rr}	reverse recovery time	when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.7	4	ns	
V _{fr}	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.8	1.75	V	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		360	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

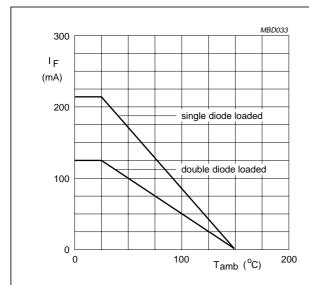
Note

1. Device mounted on an FR4 printed-circuit board.

High-speed double diode

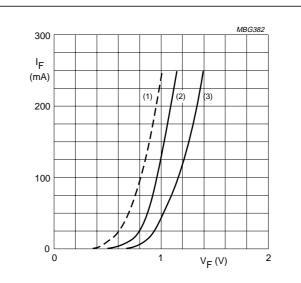
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GRAPHICAL DATA



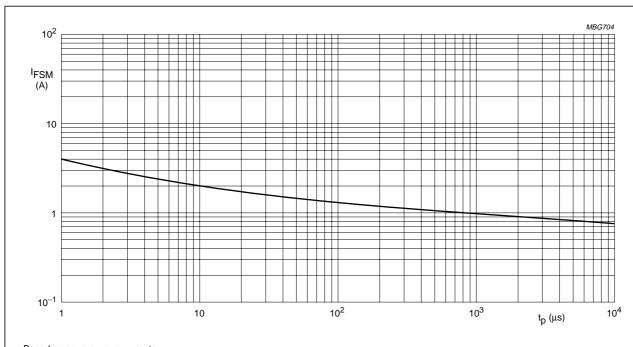
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1) $T_j = 150$ °C; typical values.
- (2) $T_j = 25$ °C; typical values.
- (3) $T_j = 25$ °C; maximum values.

Fig.3 Forward current as a function of forward voltage.

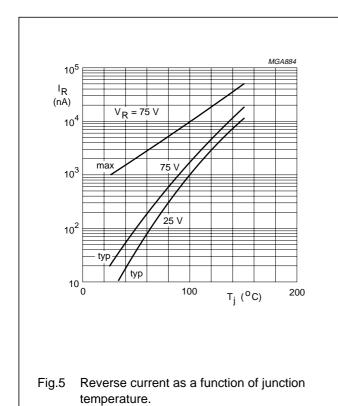


Based on square wave currents. $T_i = 25$ °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

High-speed double diode

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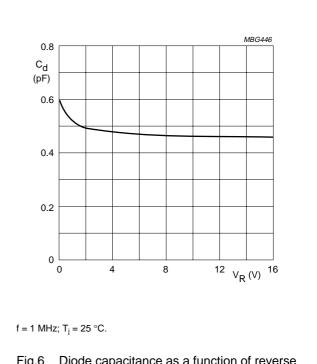
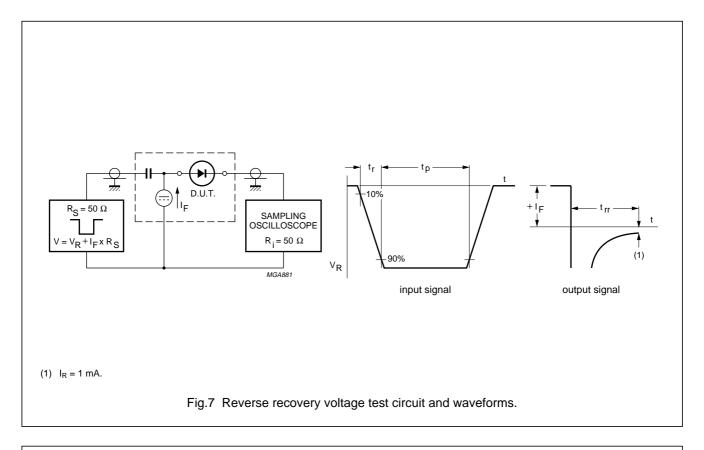
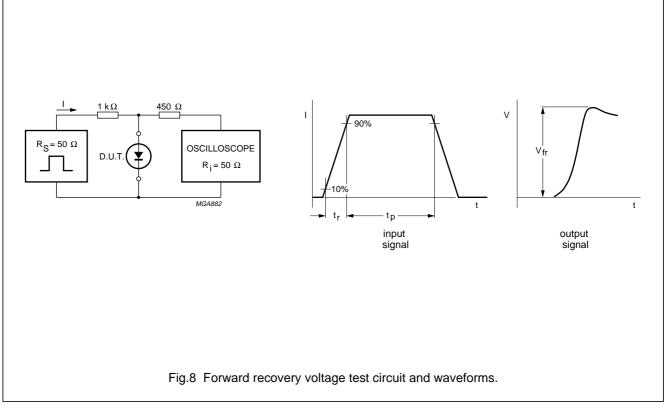


Fig.6 Diode capacitance as a function of reverse voltage; typical values.

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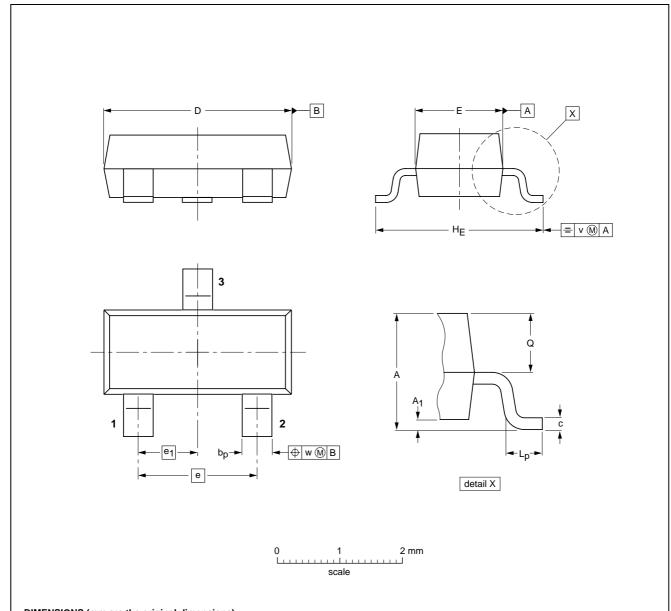
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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



DIMENS	IONS (m	ım are t	ne orıgır	nai dime	nsions)	
						-

UNIT	A	A ₁ max.	bp	С	D	E	е	e ₁	HE	L _p	Q	v	w	
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1	

	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
,	VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
	SOT23		TO-236AB				-97-02-28- 99-09-13

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

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